## NSN 5961-01-376-1575

Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-376-1575 **Inclosure Material:** Plastic or ceramic or glass **Overall Length:** Between 0.250 inches and 0.310 inches **Terminal Length:** Between 1.000 inches and 1.300 inches **Overall Diameter:** 0.185 inches **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Cubic Measure:** 0.030 cubic inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 2000.0 working peak reverse voltage, peak total value and 3.5 forward voltage, dc **Current Rating Per Characteristic:** 2.00 amperes forward current, average absolute and 1.00 microamperes forward current, average peak **Capacitance Rating In Picofarads:** 25.0 **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No